CLAIMS

- 1 1. A method for fabricating a magnetic head including a spin valve sensor, comprising
- 2 the steps of:
- fabricating a first electrical insulation layer (G1) above a first magnetic shield layer (S1);
- 4 fabricating a plurality of spin valve sensor layers above said G1 layer, said spin valve
- 5 sensor layers including a seed layer, a PtMn antiferromagnetic layer, at least one pinned
- 6 magnetic layer and at least one free magnetic layer;
- 7 wherein said seed layer is a three part seed layer comprised of Al₂O₃, NiMnO and
- 8 NiFeCr.

13

- 2. A method for fabricating a magnetic head as described in claim 1 wherein said NiFeCr seed layer portion is fabricated to have a thickness of approximately 20 Å.
- 3. A method for fabricating a magnetic head as described in claim 1 wherein said spin valve sensor layers include at least one pinned magnetic layer having a composition including CoFe and at least one spacer layer having a composition including Cu, and at least one free magnetic layer having a composition including NiFe.
- 1 4. A method for fabricating a magnetic head as described in claim 1 wherein the Cr
- 2 concentration of said NiFeCr layer is from approximately 35 at.% to approximately 46 at.%.
- 1 5. A method for fabricating a magnetic head as described in claim 4 wherein the Cr
- 2 concentration of said NiFeCr layer is approximately 38 at.%.

- 1 6. A method for fabricating a magnetic head as described in claim 5 wherein the
- 2 composition of said NiFeCr layer is approximately Ni_{49.5} Fe_{12.5} Cr₃₈.
- 1 7. A method for fabricating a magnetic head including a spin valve sensor, comprising the steps
- 2 of:
- fabricating a first electrical insulation layer (G1) above a first magnetic shield layer (S1);
- 4 fabricating a plurality of spin valve sensor layers above said G1 layer, said spin valve
- 5 sensor layers including a seed layer, a PtMn antiferromagnetic layer, at least one pinned
- 6 magnetic layer and at least one free magnetic layer;
 - wherein said seed layer is comprised of Al₂O₃, NiMnO, NiFeCr layer portions, and
 - wherein said NiFeCr layer is fabricated by depositing it to a first thickness and subsequently
 - etching it back to a final thickness before the fabrication of said PtMn layer.
 - 8. A method for fabricating a magnetic head as described in claim 7 wherein said NiFeCr
 - layer is fabricated to have a final thickness of from approximately 10 Å to approximately 40 Å.
- 1 9. A method for fabricating a magnetic head as described in claim 8 wherein said NiFeCr
- 2 seed layer is fabricated to have a final thickness of from approximately 15 Å to approximately 35
- 3 Å.
- 1 10. A method for fabricating a magnetic head as described in claim 9 wherein said NiFeCr
- 2 layer is fabricated to have a final thickness of approximately 20 Å.

- 1 11. A method for fabricating a magnetic head as described in claim 7 wherein said first
- 2 thickness of said NiFeCr layer is from approximately 15 Å to approximately 45 Å and it is
- 3 etched back a thickness of from approximately 5 Å to approximately 15 Å.
- 1 12. A method for fabricating a magnetic head as described in claim 11 wherein said first
- 2 thickness is approximately 30 Å and said final thickness is approximately 20 Å.
- 1 13. A method for fabricating a magnetic head as described in claim 7 wherein said spin valve
- 2 sensor layers include at least one pinned magnetic layer having a composition including CoFe
 - and at least one spacer layer having a composition including Cu, and at least one free magnetic
 - layer having a composition including NiFe.

 $\square 3$

- 14. A method for fabricating a magnetic head as described in claim 7 wherein the Cr concentration of said NiFeCr layer is from approximately 35 at.% to approximately 46 at.%.
- 15. A method for fabricating a magnetic head as described in claim 14 wherein the Cr
- 2 concentration of said NiFeCr layer is approximately 38 at.%.
- 1 16. A method for fabricating a magnetic head as described in claim 15 wherein the
- 2 composition of said NiFeCr layer is approximately Ni_{49.5} Fe_{12.5} Cr₃₈.
- 1 17. A method for fabricating a magnetic head as described in claim 7 wherein said first
- 2 thickness is from 15 to 45 Å, and it is etched back a thickness of from 5 to 15 Å, and wherein the

- 3 Cr concentration of said NiFeCr layer composition is from approximately 35 at.% to
- 4 approximately 46 at.%.
- 18. 1 A magnetic head including a spin valve sensor comprising:
- 2 a magnetic shield layer (S1) being fabricated above a substrate base;
- 3 a first electrical insulation layer (G1) being fabricated above said S1 layer;
- 4 a spin valve sensor structure being disposed above said G1 layer;
- 5 wherein said spin valve sensor structure includes a seed layer being fabricated above said
- 6 G1 layer, a PtMn layer being disposed above said seed layer and at least one pinned magnetic
- **T**7 layer and at least one free magnetic layer being disposed above said PtMn layer; and
- wherein said seed layer includes an Al₂O₃ layer, an NiMnO layer, and an NiFeCr layer.
 - 19. A magnetic head as described in claim 18 wherein said NiFeCr layer is formed with a thickness of approximately 20 Å.
 - 20. A magnetic head as described in claim 18 wherein the Cr concentration of said NiFeCr
 - 2 layer is from approximately 35 at.% to approximately 46 at.%.
 - 1 21. A magnetic head as described in claim 19 wherein the Cr concentration of said NiFeCr
 - 2 layer is approximately 38 at.%.
 - A magnetic head as described in claim 21 wherein the composition of said NiFeCr layer 1 22.
 - 2 is approximately Ni_{49.5} Fe_{12.5} Cr₃₈.

- 23. 1 A magnetic head including a spin valve sensor comprising:
- 2 a magnetic shield layer (S1) being fabricated above a substrate base:
- 3 a first electrical insulation layer (G1) being fabricated above said S1 layer:
- 4 a spin valve sensor structure being disposed above said G1 layer:
- 5 wherein said spin valve sensor structure includes a seed layer being fabricated above said
- G1 layer, a PtMn layer being disposed above said seed layer and at least one pinned magnetic 6
- layer and at least one free magnetic layer being disposed above said PtMn layer; and 7
- 8 wherein said seed layer has an upper surface comprised of NiFeCr having an etched
- 9 crystalline structure.

- A magnetic head as described in claim 23 wherein said NiFeCr layer is formed with a 24. thickness of from approximately 10 Å to approximately 40 Å.
- A magnetic head as described in claim 23 wherein said NiFeCr seed layer is formed with 25. a thickness of from approximately 15 Å to approximately 35 Å.
- 1 magnetic head as described in claim 23 wherein said NiFeCr layer is formed with a 26.
 - 2 thickness of approximately 20 Å.
 - A magnetic head as described in claim 23 wherein the Cr concentration of said NiFeCr 1 27.
 - 2 layer is from approximately 35 at.% to approximately 46 at.%.

- A magnetic head as described in claim 27 wherein the Cr concentration of said NiFeCr 28. 1
- layer is approximately 38 at.%. 2
- A magnetic head as described in claim 28 wherein the composition of said NiFeCr layer 1 29.
- 2 is approximately Ni_{49.5} Fe_{12.5} Cr₃₈.
- A magnetic head as described in claim 23 wherein said spin valve sensor structure 1 30.
- includes at least one PtNm antiferromagnetic layer, at least one pinned magnetic layer having a 2
- composition which includes CoFe, at least one spacer layer having a composition which includes 3
- Cu, and at least one free magnetic layer having a composition which includes NiFe.
- 1 2 3 4 5 5 A hard disk drive, including at least one magnetic head having a read head portion 31. comprising:
 - a magnetic shield layer (S1) being fabricated above a substrate base;
 - a first electrical insulation layer (G1) being fabricated above said S1 layer;
 - a spin valve sensor structure being disposed above said G1 layer;
 - wherein said spin valve sensor structure includes a seed layer being fabricated above said 6
 - G1 layer, a PtMn layer being fabricated above said seed layer and at least one pinned magnetic 7
 - layer and at least one free magnetic layer; and 8
 - wherein said seed layer includes an Al₂O₃ layer, an NiMnO layer and an NiFeCr layer. 9
 - A hard disk drive as described in claim 31 wherein said NiFeCr layer has a thickness of 1 32.
 - 2 approximately 20 Å.

- 1 33. A hard disk drive as described in claim 31 wherein the Cr concentration of said NiFeCr
- 2 layer is from approximately 35 at.% to approximately 46 at.%.
- 1 34. A hard disk drive as described in claim 33 wherein the Cr concentration of said NiFeCr
- 2 layer is approximately 38 at.%.
- 1 35. A hard disk drive as described in claim 34 wherein the composition of said NiFeCr layer
- 2 is approximately Ni_{49.5} Fe_{12.5} Cr₃₈.
 - 36. A hard disk drive, including at least one magnetic head having a read head portion comprising:
 - a magnetic shield layer (S1) being fabricated above a substrate base;
 - a first electrical insulation layer (G1) being fabricated above said S1 layer;
 - a spin valve sensor structure being disposed above said G1 layer;
 - wherein said spin valve sensor structure includes a seed layer being fabricated above said
- 7 G1 layer, a PtMn layer being fabricated above said seed layer and at least one pinned magnetic
- 8 layer and at least one free magnetic layer; and
- 9 wherein said seed layer has an upper surface comprised of NiFeCr having an etched
- 10 crystalline structure.

- 1 37. A hard disk drive as described in claim 36 wherein NiFeCr seed layer is formed with a
- 2 thickness of from approximately 10 Å to approximately 40 Å.

- 1 38. A hard disk drive as described in claim 36 wherein said NiFeCr seed layer is formed with
- 2 a thickness of from approximately 15 Å to approximately 35 Å.
- 1 39. A hard disk drive as described in claim 36 wherein said NiFeCr layer is formed with a
- 2 thickness of approximately 20 Å.
- 1 40. A hard disk drive as described in claim 36 wherein the Cr concentration of said NiFeCr
- 2 layer is from approximately 35 at.% to approximately 46 at.%.
 - 41. A hard disk drive as described in claim 40 wherein the Cr concentration of said NiFeCr
 - layer is approximately 38 at.%.
 - 42. A hard disk drive as described in claim 41 wherein the composition of said NiFeCr layer is approximately Ni_{49.5} Fe_{12.5} Cr₃₈.
- 1 43. A hard disk drive as described in claim 36 wherein said spin valve sensor structure
- 2 includes at least one PtNm antiferromagnetic layer, at least one pinned magnetic layer having a
- 3 composition which includes CoFe, at least one spacer layer having a composition which includes
- 4 Cu, and at least free magnetic layer having a composition which includes NiFe.